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RESEARCH ARTICLE

MM-Wave High Isolated Dual Polarized Dielectric Resonator Antenna for In-Band Full-Duplex Systems

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ABSTRACT A novel high-isolation dual-polarized in-band full-duplex (IBFD) dielectric resonator antenna (DRA) for satellite communications using a decoupling structure is proposed. Good isolation between transmit and receive ports is achieved by placing two identical linearly polarized resonators orthogonal to each other. Each resonator consists of a main rectangular dielectric resonator of the dielectric constant of 10 and is loaded by a thin dielectric slab of lower permittivity of 5 to broaden the matching bandwidth further. The isolation is further improved by loading an absorber and etching several slots in the ground plane. Finally, the proposed DRA is fabricated and measured to validate the concepts. Measurement results show high isolation of more than 50 dB over the desired operating bandwidth from 23.04 GHz to 24.08 GHz (ka-band) with a peak gain of about 8.93 dBi and 8.09 dBi for Port 1 and Port 2, respectively. In addition, the proposed IBFD DRA provides 11.87 GHz and 4.84 GHz isolation bandwidths over 25 dB and 30 dB, respectively, making it a potential candidate for mm-wave terrestrial applications.

INDEX TERMS Dielectric resonator antenna, dual-polarization, in-band full-duplex.

I. INTRODUCTION

In recent years, deployable electromagnetic spectra have been highly demanded by dramatically increasing data traffic in wireless communication. As an emerging new transmission technology, in-band full-duplex (IBFD) communication, which simultaneously transmits (Tx) and receives (Rx) signals over the same frequency band, has attracted immense attention as a promising technique to increase spectrum efficiency with the potential to double the channel capacity compared to that of a time/frequency division method [1], [2]. However, practically, in the IBFD system, due to the existence of high self-interference (SI) in the system, where the transmitted signal leaks to the Rx side, high isolation (as much as 110 dB) between Tx and Rx channels is required [3].

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In order to minimize the coupling in a full-duplex system, including antenna, RF, baseband, and digital domains, multilayer self-interference cancellation (SIC) approaches are needed correspo0nding to antenna isolation, active/passive analogue cancellation circuits, and digital cancellation algorithms. The main bottleneck problems with the current IBFD system design include bandwidth limitation imposed by the RF self-interference cancellation circuits and implementation complexity, and large insertion loss associated with RF SIC circuits. As such, achieving high isolation in the antenna domain relieves the burden placed on other layers and helps mitigate the overall complexity of a simultaneously transmits and receives (STAR) transceiver [4].

A plethora of full-duplex (FD) antennas with high isolation, including microstrip, cavity, and slot antennas, have been reported in the literature [5], [6], [7], [8], [9], [10], [11], [12], [13], [14], [15], [16], [17], [18], [19], [20], [21], [22], [23], [24], [25], [26]. Nevertheless, most of these designs operate at frequency bands below 20 GHz. On the other hand, there have been increasing full-duplex applications for millimetre-wave (mm-wave) transmissions for high data rate communications in the past decade. However, the inherent problems with mm-wave, such as high path loss, necessitate high gain antenna design [8]. Various techniques exist to improve the isolation between the TX and the Rx antennas [10], [11], [7], [12], [13], [14], [15], [16], [17], [18], [19], [20], [21], [22], [23], [24], [25]. Generally, these methods are divided into several main categories, such as physical separation between Tx and Rx apertures [9], [10], utilizing polarization multiplexing [11], [7], [12], [13], employing near-field cancellation [14], [15], [16], and implementing circulators [17], [18], [19]. Finally, the decoupling technique suppresses the self-interference caused by the electromagnetic coupling between the Tx and Rx antennas [20], [21], [22], [23], [24], [25]. For example, in [22], a radiating element is applied between Rx and Tx antennas, coupling power from the Tx antenna. It is orthogonally polarized and re-radiates the power to minimize the original field around the Rx antenna. Furthermore, in [24], a power distributing duplex network is employed to obtain high isolation of about 45 dB between the two input ports. As for the one presented in [25], the electromagnetic bandgap (EBG) structure is inserted between two closely located monopole antennas to improve isolation. As a result, the achieved isolation is up to 50 dB in 110 MHz bandwidth at around 2.5 GHz. However, generally speaking, most of the works, as mentioned earlier, suffer from a high cost, a large antenna dimension, narrow bandwidth, low radiation efficiency, or a complex structure.

Here, we propose a high isolation dual-polarized IBFD dielectric resonator antenna (DRA) at mm-wave with high radiation efficiency for the first time that can be extended to an IBFD array DRA achieving desirable gain for satellite communications. DRAs have been extensively studied in past decades because of their remarkable features, such as low loss, no surface wave, high radiation efficiency, various excitation mechanisms, and geometrical flexibility [26], [27]. In addition, the 3-D geometry of DRAs offers a higher degree of flexibility over microstrip antennas that suffer from narrow bandwidth and low radiation efficiency [28]. In addition, we use the feature of low coupling between DRAs of high order odd index in the z-direction [29]. High isolation better than 50 dB is realized by loading a thin rectangular dielectric resonator (DR) attached to two strips at the top and the bottom, applying a vertical strip connected to both the ground plane and thin DR, and etching several slots in the ground plane. The configuration and the design procedure, a numerical study on designing IBFD DRA, the effects of loading thin DRs, the impact of adding decoupling structure and etching the slots in the ground plane, and the measurement results on fabricated prototype are discussed in the following sections.

II. ANTENNA CONFIGURATION AND PHYSICAL WORKING MECHANISM

A rectangular DR (RDR) offers more design parameters, such as two different aspect ratios (width/length and height/length) in a desired resonant frequency compared to the spherical and cylindrical ones. Parallelly, in IBFD antenna design, although there are various techniques to achieve 50 dB antenna isolation, the supported bandwidth is narrow and suffers from the large size, complexity, or dissimilar transmit/receive radiation.

The evolution of the proposed high-isolation dualpolarized IBFD DRA is demonstrated in Fig. 1. Fig. 1(a) shows the initial design of the proposed antenna, including two identical RDRs (DR_1) with the same dimensions $a_1 \times b_1 \times h_1$ and permittivity of $\varepsilon_{DR_1} = 10$ supported by a grounded $23(x-axis)mm \times 14.1(y-axis)mm$ Rogers RT5880 substrate with a permittivity of $\varepsilon_s = 2.2$ and a thickness of s = 0.127 mm, where maximum isolation of about 43 dB is achieved. The RDRs are excited by a microstrip feed line through a rectangular metal strip $l_5 \times w_6$. Then, another two small identical RDRs (DR_2) with the exact dimensions of $a_3 \times b_3 \times h_3$ and permittivity of $\varepsilon_{DR_2} = 5$ are attached to the previous RDRs with a reducing length from 4mmto3.5 mm to improve the impedance matching (please see Fig. 1(c)), denoted as Antenna I. To further improve the isolation, two slots with $l_3 \times w_2$ are etched in the ground plane in the transverse direction of each microstrip feed line (please see Fig. 1(d)), denoted as Antenna II. Finally, a new decoupling structure, including a vertical and two horizontal strip patches, a slot in the ground plane, and a thin RDR (DR_3) with a dimension of $a_4 \times b_4 \times h_4$ and a dielectric constant of $\varepsilon_{DR_m} = 10$, is introduced to enhance the isolation bandwidth (please see Fig. 1(e)), denoted as Antenna III. All DRs have a relative loss tangent $tan \delta = 1.54 \times 10^{-5}$.

In this work, CST Microwave Studio 2021 is employed to analyze and optimize the proposed IBFD DRA. The ultimate aim of this design is to propose a new dual-polarized antenna with high isolation to realize full-duplex radio transmissions over satellites considering two crucial parameters; antenna efficiency and isolation. The main contribution of this work is to propose a dual-polarized DRA with 50 dB wide isolation bandwidth between the Tx and Rx ports and efficiency higher than 93% at the Ka-band, which is the first of its kind. This section describes the working principle of the proposed IBDF DRA and the physical mechanisms, which include three steps as follows:

- I Loading a small rectangular dielectric slab with a dielectric constant of 5 to improve the maximum isolation from 42 dB to 55 dB with an isolation bandwidth of 170 MHz over 50 dB.
- II Adding slots on top of the feed lines improves the isolation between two ports from 55 to 62 dB and enhances the bandwidth from 170 MHz to 270 MHz for the 50 dB threshold.



FIGURE 1. Evolution of the proposed IBFD DRA: (a) initial structure of IBFD DRA, (b) back view of the proposed antenna(microstrip feed lines), (c) adding two small RDRs with low permittivity to the initial structure, forming Antenna I, (d) applying narrow slots in the ground plane of Antenna I, denoting Antenna II, (e) adding an absorber with an opening slot beneath it to the Antenna II, namely Antenna III, and (f) 3D view of the proposed antenna (Antenna III). ($l_g = 14.1$, $w_g = 23$, $l_1 = 0.185$, $l_2 = 0.3$, $l_3 = 0.4$, $l_5 = 1.9$, $l_6 = 2.7$, $w_d = 5.8$, $w_1 = 1.4$, $w_2 = 3.5$, $w_3 = 0.4$, $w_4 = 1.4$, $w_5 = w_7 = 0.5$, $w_6 = 1$, $l_{ms} = 0.7.1$, $w_{ms} = 0.36$, $a_1 = 4$, $b_1 = b_2 = b_3 = 2$, $h_1 = h_2 = h_3 = 4.7$, $a_2 = 3.5$, $a_3 = 0.5$, $a_4 = 7$, $b_4 = 3.8$, $h_4 = 0.5$, $\varepsilon_{DR_1} = \varepsilon_{DR_m} = 10$, $\varepsilon_{DR_2} = 5$, $\varepsilon_s = 2.2$, s = 0.127. Unit : mm).

III Applying a decoupling structure remarkably improves the isolation bandwidth from 270 MHz to 1090 MHz over 50 dB with peak isolation of 70 dB.

III. IBFD DRA DESIGN ANALYSIS

As shown in Fig. 1(a), the initial dual-polarized IBFD DRA is realized by two RDRs with equal dimensions $a_1 \times b_1 \times h_1$ $(a_1 \text{ and } h_1 \gg b_1)$ orthogonally excited by vertical metal strips attached to the DRA side wall and connected to microstrip feed lines (in the bottom side of a dielectric substrate) through a narrow rectangular hole to realize the dual-polarized performance. The distance between DRs (wall-to-wall) is defined as $w_d = 0.58\lambda$. The proposed antenna system has two ports: one supports TE_{mnp}^x mode for Tx and the other one supports TE_{mnp}^y mode for Rx. Both input and output ports of the system can operate simultaneously. The dielectric waveguide model (DWM) equations are used to predict the resonant frequency f_r of TE_{mnp} modes excited inside the proposed DRA [30]:

$$f_r = \frac{1}{2 \pi \sqrt{\varepsilon_{DR}}} \sqrt{k_x^2 + k_y^2 + k_z^2}$$
(1)

where k_x , $k_y = n\pi/a$, and $k_z = p\pi/2h$ are the mode wave numbers within the RDR. The following characteristic Equation should be solved for k_x for each mode index *m* for a variable k_0

$$k_x tan(\frac{bk_x - (m-1)\pi}{2}) = \sqrt{(\varepsilon_{DR} - 1)k_0^2 - k_x^2}$$
(2)

The solution for each m determines the other mode indices n and p in the y- and z-directions.

In order to improve the impedance bandwidth, a small rectangular dielectric slab with dimension $a_3 \times b_3 \times h_3$ and dielectric constant $\varepsilon_{DR_2} = 5$ is added to each previous RDR with reduced length to $a_2 \times b_2 \times h_2$ ($a_2 = 3.5 \text{ mm}$; $b_1 = b_2$, $h_1 = h_2$) (please see Fig. 1 (c)), namely as Antenna I. It is noted that the new resonant frequency can be calculated by substituting ε_{DR_1} with ε_{eff} (effective dielectric constant) in Equation (2) [27], where

$$\varepsilon_{eff} = \frac{a_1 + a_2}{\frac{a_1}{\varepsilon_{DR_1}} + \frac{a_2}{\varepsilon_{DR_2}}} \tag{3}$$

Figure 2 illustrates the simulated s-parameters of the initial structure of IBFD DRA and Antenna I (please see Fig. 2) (a) and (b)) and E-field distribution inside the DRs (please see Fig. 2 (c)) for the Antenna I at 23.5 GHz. It is observed from Fig. 2 (a) that the RDRA provides a wide impedance bandwidth of about 60% (Port 1) and 58% (Port 2), and exciting resonant modes across the operating frequency resembles TE_{111} , TE_{113} , and TE_{115} modes. Maximum isolation of 43 dB at 23.5 GHz is obtained, corresponding to TE_{113}^x and TE_{113}^y modes (please see Fig. 2 (c)). In the next step (refer to Fig. 1(c)), by loading two thin RDRs ($\varepsilon_{DR_2} = 5$), the impedance matching and the mutual coupling between two orthogonal resonators is improved due to decreasing the O-factor of the resonators, resulting in better matching with enhanced isolation to a maximum of about 55 dB, as shown in Fig. 2 (a) and (b).



FIGURE 2. Simulated S-parameters of the initial structure of IBFD DRA and Antenna I and E-field distribution inside the RDRs for Antenna I. (a) $|S_{11}|$ and $|S_{22}|$, (b) $|S_{12}| = |S_{21}|$, and (c) $\mathcal{TE}_{113}^{\mathcal{Y}}$ mode at 23.5 GHz (left resonator).



FIGURE 3. Simulated S-parameters of Antenna I and Antenna II (added slots). (a) $|S_{11}|$ and $|S_{22}|$, (b) $|S_{12}| = |S_{21}|$.

ADDING DECOUPLING STRUCTURE TO IMPROVE THE ISOLATION

As shown in Fig. 1 (d), four identical slots with key parameters of $l_3 \times w_2$ are etched in the ground plane on top of the feed lines to improve the isolation between two ports, namely Antenna II.

Figure 3 shows the simulated S-parameters of the IBFD DRA with and without the slots. By etching four equal rectangular slots, the isolation between Tx and Rx channels is enhanced to 62 dB with an isolation bandwidth ranging from 23.41 GHz to 23.68 GHz over 50 dB. In this way, the slots act as matching stubs. Consequently, the coupling current on the ground plane is reduced by generating opposite currents around the slots, resulting in improved isolation.

Finally, for further minimizing the mutual coupling and enhancing the isolation bandwidth, a decoupling structure, including a thin RDR (DRm) slab with dimensions $a_4 \times b_4 \times h_4$ and dielectric constant $\varepsilon_{DR_m} = 10$, placed between two parallel metal strips at the top and the bottom, all connected to a vertical standing strip, is introduced, namely Antenna III. Fig. 4 shows the exploded view of the proposed



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FIGURE 4. Exploded view of the proposed absorber.



FIGURE 5. Simulated Tx-to-Rx coupling of the proposed antenna (a) with and without each element of decoupling structure separately and (b) with different DRm permittivity.

absorber, shedding light on the proposed absorber design consideration. First, a vertical standing strip is connected to the ground plane at the bottom and a parasitic strip at the top to improve the isolation bandwidth from 270 MHz to 475 MHz over 50 dB. Then, a second parasitic strip, parallel to the first one by 0.5 mm distance in the z-direction, is applied to further enhance the isolation bandwidth by 210 MHz (from 475 MHz to 685 MHz over 50 dB). A 0.4 (x-axis) $mm \times 7$ (y-axis) mm slot is etched on the ground plane to increase the isolation by 10 dB, from 63 dB to 73 dB. Finally, a dielectric slab with a permittivity of 10 and thickness of 0.5 mm is horizontally placed between two parallel strips to improve the isolation bandwidth further, shown in Fig. 5 (a). Fig. 5 (b) illustrates the simulated Tx-to-Rx coupling of the proposed antenna with different values of DR permittivity $\varepsilon_{DR_m} = 0, 8, 10, \text{ and } 12.$ According to the figure, a wider isolation bandwidth is achieved by using a permittivity of $\varepsilon_{DR_m} = 10$ to design the proposed absorber. The effect of the decoupling structure on the antenna performance is exhibited in Fig. 6. It is observed from Fig.6 (b) that by implementing the decoupling structure between two resonators, the isolation bandwidth is remarkably improved from 240MHz in Antenna II to 1090 MHz in Antenna III. The simulated electric field vectors on different surfaces of the DRs and current distribution for Antenna III at 23.5 GHz are illustrated in Fig. 6 (c), (d), and (e), respectively. By applying the proposed decoupling structure, the EM waves between two resonators are absorbed by DRm. Consequently, a sharp contrast between





FIGURE 6. Simulated S-parameters of the Antenna II and the Antenna III and E-field and current distributions for Antenna III. (a) reflection coefficient, (b) Tx-to-Rx coupling, (c) modes inside each DR block, and surface current distributions for the Antenna III at 23.5 GHz when (d) Port 1 and (e) Port 2 are excited.



FIGURE 7. The prototype of the proposed IBFD dual-polarized DRA. (a) back view and (b) 3D view.

the current distributions on the left and right side of the decoupling elements leads to significantly enhanced isolation bandwidth between the Tx and Rx ports.

IV. EXPERIMENTAL RESULTS

As illustrated in Fig. 7, a prototype of the proposed IBDF dual-polarized DRA is simulated, fabricated, assembled, and measured to verify the performance of the proposed antenna. A ROHACELL®. HF Foam ($\varepsilon_{ro} = 1.04$) is glued beneath the DRm using RTV silicone adhesive ($\varepsilon_g = \approx 3$) to assemble the decoupling elements between the Rx and Tx resonators.

S-PARAMETER MEASUREMENT

The simulated and measured S-parameters of the proposed IBDF dual-polarized DRA are depicted in Fig. 8, representing a close agreement between the simulated and measured







FIGURE 9. Simulated and measured far-field radiation patterns of the proposed IBFD DRA in *xz*-plane ($\phi = 0^{\circ}$) and *yz*-plane ($\phi = 90^{\circ}$) at 23.5 GHz; (a) Port 1 and (b) Port 2.

results except for a slight discrepancy caused by the fabrication errors and manually assembling imperfection. The proposed IBFD DRA provides a perfectly overlapping ultra-wide impedance bandwidth for Ports 1 and 2. As shown in Fig. 8, the proposed DRA provides isolation higher than 50 dB in the desired bands, ranging from 22.93 GHz to 24.02 GHz and 23.04 GHz to 24.08 GHz for the simulation and the

Ref.	f_c (GHz)	BW (GHz)	Dimensions(λ^3)	Isolation(dB)	Tx/Rx peak gain	G/V	Efficiency
[5]	3.57	3.35-3.8	$0.45 \times 0.2 \times 0.04$	≥ 43	2.8/2.8	777	≥70
[12]	2.45	2.4-2.62	$1.17 \times 1.69 \times 0.05$	≥ 35.9	8.02	81	NA
[18]	2.55	2.4-2.7	$0.98 \times 0.98 \times 0.15$	40	1.8/3.3	22	NA
[21]	2.4	2.3-2.6	\gg 3.68×1.63	≥ 45	3	$\ll 0.5$	≥90
[22]	6.29	6.24-6.34	$0.63 \times 0.63 \times 0.08$	≥ 25	3.87/7.58	236	≥ 75
[23]	2.45	2.42-2.47	$0.54 \times 0.18 \times 0.06$	30	-1.6	274	≤ 60
[24]	5.8	5.62-6.11	$1.2 \times 1.07 \times 0.578$	50	5.3/6	8	NA
This work	23.56	23.04-24.08	1.8 imes 1.1 imes 0.39	≥ 50	8.93/8.09	12	≥ 93

 TABLE 1. Comparison with IBFD Antennas in the literature.

 f_c : center frequency, BW: overlapping bandwidth, and G/V: gain to volume.



FIGURE 10. Simulated total efficiency and measured gain of the proposed antenna.

measurement. It is noted that the maximum measured and simulated isolation within the studied band are up to 65.21 dB at 23.58 GHz and 76.43 dB at 23.78 GHz, respectively.

A. FAR-FIELD MEASUREMENT

Figure 9 illustrates the simulated and the measured far-field radiation patterns of the proposed IBFD DRA in the *xz*-plane $(\phi = 0^{\circ})$ and *yz*-plane $(\phi = 90^{\circ})$ at 23.5 GHz. It is observed that the simulated and measured radiation patterns are in good agreement, where the proposed DRA's radiation patterns remain stable within the desired operating band, and the difference between Co- and cross-polarization radiation levels is more than 21 dB confirming the purity of the radiation. It is worth mentioning that the proposed antenna provides a total efficiency higher than 93% in the desired frequency bands (23.04 GHz to 24.08 GHz) with a maximum gain corresponding to Port 1 and Port 2 of about 9.36 dBi and 8.57 dBi for simulation, and 8.93 dBi and 8.09 dBi for measurements, respectively, shown in Fig. 10.

B. COMPARISON WITH THE LITERATURE

The state-of-the-art high isolation antennas are summarized and listed in Table 1 for comparisons in terms of the critical performance metrics. It is found that the proposed antenna offers higher isolation with higher gain and efficiency using a simple single-substrate design and feeding structure. Wang et al. [12] proposed a reflective terminal approach to improve isolation. Compared to [12], where double substrate topology is used, the proposed design offers higher isolation with a simple single substrate design. Moreover, the antennas in [17], [20], and [22] suffer poor isolation performances. The antennas in [5] and [21] have high isolation but with a reduced low gain. In the design in [23], although high isolation of up to 50 dB is achieved, the employed structure cannot be extended to mm-wave and suffer from low efficiency.

V. CONCLUSION

A dual-polarized in-band full-duplex dielectric resonator antenna has been presented. Two dielectric resonators with different dielectric constants were employed to improve the impedance bandwidth with better isolation. A decoupling element was incorporated to further isolation improvement, including three metal strips and a dielectric resonator to provide a high isolation bandwidth. The proposed antenna was fabricated, assembled, and measured. The measured results have demonstrated high isolation, within frequency ranging from 23.04 to 24.08. The maximum realized gain of 8.93 dBi and 8.09 dBi for Ports 1 and 2, respectively. The proposed IBFD dual-polarized DRA offers a high gain antenna with high isolation, which is a potential candidate for the in-band full-duplex applications at mm-wave frequencies, especially for ka-band satellite communications. Furthermore, the proposed antenna provides 11.87 GHz and 4.84 GHz isolation bandwidths over 25 dB and 30 dB, respectively, which could be utilized for mm-wave terrestrial applications.

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